CRYSTAL OSCILLATOR SPXO

SG-615 series SG-531/SG-51 series

•Frequency range : 1.025 MHz to 135 MHz

•Supply voltage : 3.3 V / 5.0 V

•Function : Output enable(OE) Standby($\overline{\text{ST}}$) •Pin compatible with full-size metal can. (SG-51 series) •Pin compatible with half-size metal can. (SG-531 series)



Specifications (characteristics)

Item		Symbol		Specifications		
			SG-615P SG-531P	SG-615PTJ SG-531PTJ	SG-615PH SG-531PH	Remarks
0 1 11			SG-51P	SG-51PTJ	SG-51PH	
Output frequency range		f ₀	1.025 MHz to 26 MHz	26.001 MHz to	66.667 MHz	
Supply voltage		Vcc	5.0 V ±0.5 V			
	Storage temperature	T_stg	-55 °C to +125 °C			Store as bare product after unpacking
	Operating temperature	T_use	-20 °C to +70 °C			
Frequency tolerance		F_tol(osc)	B: ±50 × 10 ⁻⁶ , C: ±100 × 10 ⁻⁶			-20 °C to +70 °C *1
Current consumption		Icc	23 mA Max.	35 mA Max.		No load condition
Output disable current		l_dis	12 mA Max.	28 mA Max.	20 mA Max.	OE=GND
Symmetry		SYM	40 % to 60 %		40 % to 60 %	CMOS load:50 % Vcc level
			40 % to 60 %	45 % to 55 %	_	TTL load: 1.4 V level
High output voltage		Vон	Vcc-0.4 V Min.	2.4 V Min.	Vcc-0.4 V Min.	IOH=-400 μA(P,PTJ)/-4 mA(PH)
Low output voltage		Vol	0.4 V Max.			IoL=16 mA(P)/ 8 mA(PTJ)/ 4 mA(PH)
Output load condition (TTL)		L_TTL	10 TTL Max.	5 TTL Max.	_	L_CMOS ≤ 15 pF
Output load condition (CMOS)		L_CMOS	50 pF Max.		50 pF Max.	
Output enable / disable input voltage		Vih	2.0 V Min.	3.5 V Min.	2.0 V Min.	Iιн= 1 μA Max. (OE=Vcc)
		VIL	0.8 V Max.	1.5 V Max.	0.8 V Max.	IIL= -100 μA Min. (OE=GND), PTJ:IIL= -500 μA Min.(OE=GND)
Output rise and fall time		t r / t f	8 ns Max.	_	7 ns Max.	CMOS load:20 % Vcc to 80 % Vcc level
			8 ns Max.	5 ns Max.	_	TTL load:0.4 V to 2.4 V level
Oscillation start up time		tosc	4 ms Max. 10 ms Max.		Time at minimum supply voltage to be 0 s	
Frequency aging		F_aging	$\pm 5 \times 10^{-6}$ / year Max.			+25 °C, Vcc=5.0 V, First year

^{*1 &}quot;B" tolerance will be available up to 55 MHz.

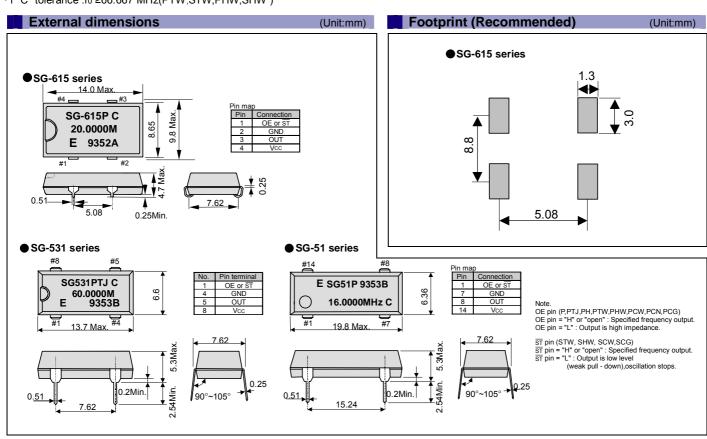
Specifications (characteristics)

Item		Symbol	Specifications				
			SG-615PCG SG-531PCG	SG-615SCG SG-531SCG	SG-615PCN	Remarks	
Output frequency range		f o	1.500 MHz to 26.000 MHz		26.001 MHz to 66.667 MHz		
Supply voltage		Vcc	2.7 V to 3.6 V		3.0 V to 3.6 V		
Temperature	Storage temperature	T_stg	-55 °C to +125 °C			Store as bare product after unpacking	
	Operating temperature	T_use	-40 °C to +85 °C				
Frequency tolerance		F 4-1/)	B: ±50 × 10 ⁻⁶ C: ±100 × 10 ⁻⁶			-20 °C to +70 °C	
		F_tol(osc)	M: ±100 × 10 ⁻⁶			-40 °C to +85 °C	
Current consumption		lcc	12 mA Max.		20 mA Max.	No load condition	
Output disable current		l_dis	10 mA Max. —		10 mA Max.	OE=GND (PCG,PCN)	
Stand-by current		I_std	-	50 μA Max.	_	ST =GND (SCG)	
Symmetry		SYM	45 % to 55 %		50 % Vcc level, L_CMOS=Max.		
High output voltage		Vон	Vcc-0.4 V Min.		Vcc-0.4 V Min.	IoH=-8 mA	
Low output voltage		Vol	0.4 V Max.		0.4 V Max.	IoL= 8 mA	
Output load condition		L_CMOS	25 pF Max.		15 pF Max.		
Output enable /		Vih	70 % Vcc Min.		70 % Vcc Min.	OE Terminal , ST Terminal	
disable input voltage		VIL	20 % Vcc Max.		30 % Vcc Max.	OL Terrimar, ST Terrimar	
Output rise and fall time		tr/tf	4 ns Max.		20 % Vcc to 80 % Vcc level, L_CMOS ≤ Max.		
Oscillation start up time		tosc	12 ms Max.		10 ms Max.	t=0 at 90% Vcc	
Frequency aging		F_aging	$\pm 5 \times 10^{-6}$ / year Max.		+25 °C, Vcc=3.3 V, First year		

Specifications (characteristics)

Item				Specifications			
		Symbol	SG-615PTW / STW	SG-615PHW / SHW	SG-615PCW / SCW	Remarks	
			SG-531PTW / STW	SG-531PHW / SHW	SG-531PCW / SCW		
Output frequency range		f o	55 001 MHz to	135.000 MHz	26.001 MHz to		
Output frequency range					135.000 MHz		
Supply voltage		Vcc	5.0 V ±0.5 V		3.3 V ±0.3 V		
Temperature	Storage temperature	T_stg	-55 °C to +125 °C			Store as bare product after unpacking	
	Operating temperature	T_use	-20 °C to +70 °C		-40 °C to +85 °C		
		F tol(osc)	B: ±50 × 10 ⁻⁶ , C: ±100 × 10 ⁻⁶			-20 °C to +70 °C *1	
Frequency to	Frequency tolerance		-	_	M: $\pm 100 \times 10^{-6}$	-40 °C to +85 °C	
Current consumption		lcc	45 mA Max.		28 mA Max.	No load condition(Max. frequency range)	
Output disable current		l_dis	30 mA Max.		16 mA Max.	OE=GND (PTW,PHW,PCW)	
Stand-by current		I_std	50 μA Max.			ST =GND (STW,SHW,SCW)	
Symmotry		SYM	— 40 % to 60 %			50 % Vcc level, L_CMOS=Max.	
Symmetry	Symmetry		40 % to 60 %			1.4 V level ,L_CMOS=Max.	
High output voltage		Vон	Vcc-0.4 V Min.			IOH=-16 mA(PTW,STW,PHW,SHW),-8 mA(PCW,SCW)	
Low output voltage		Vol	0.4 V Max.			IoL= 16 mA(PTW,STW,PHW,SHW), 8 mA(PCW,SCW)	
Output load condition (TTL)		L_TTL	5 TTL Max.	_	_	fo ≤ 90 MHz , Max.supply voltage	
Output load condition (CMOS)		L_CMOS	15 pF Max.			Max.frequency , Max.supply voltage	
Output enable /		Vih	2.0 V Min.		70 % Vcc Min.	OE Terminal , ST Terminal	
disable input voltage		VIL	0.8 V Max.		20 % Vcc Max.		
Output rice or	nd fall time	tr/tf	— 4 ns Max.			20 % Vcc to 80 % Vcc level, L_CMOS ≤ Max.	
Output rise and fall time			4 ns Max.		_	0.4 V to 2.4 V level	
Oscillation start up time		tosc	10 ms Max			Time at minimum supply voltage to be 0 s	
Frequency aging		F_aging	$\pm 5 \times 10^{-6}$ / year Max.			+25 °C, Vcc=5.0 V / 3.3 V, First year	

*1 "C" tolerance :fo ≥66.667 MHz(PTW,STW,PHW,SHW)



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In order to meet customer needs in a rapidly advancing digital, broadband and ubiquitous society, we are committed to offering products that are one step ahead of the market and a rank above the rest in quality. To achieve our goals, we follow a "3D (three device) strategy" designed to drive both horizontal and vertical growth. We will to grow our three device categories of "Timing Devices", "Sensing Devices" and "Optical Devices", and expand vertical growth through a combination of products from these categories.

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PROMOTION OF ENVIRONMENTAL MANAGEMENT SYSTEM CONFORMING TO INTERNATIONAL STANDARDS

At Epson Toyocom, all environmental initiatives operate under the Plan-Do-Check-Action(PDCA) cycle designed to achieve continuous improvements. The environmental management system (EMS) operates under the ISO 14001 environmental management standard.

All of our major manufacturing and non-manufacturing sites, in Japan and overseas, completed the acquisition of ISO 14001 certification.

In the future, new group companies will be expected to acquire the certification around the third year of operations.

ISO 14000 is an international standard for environmental management that was established by the International Standards Organization in 1996 against the background of growing concern regarding global warming, destruction of the ozone layer, and global deforestation.

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Epson Toyocom has acquired QS-9000 certification, which is of a higher level.

Also, TS 16949 certification, which is also of a higher level, has been acquired.

QS-9000 is an enhanced standard for quality assurance systems formulated by leading U.S.automobile manufacturers based on the international ISO 9000 series.

ISO/TS 16949 is a global standard based on QS-9000, a severe standard corresponding to the requirements from the automobile industry.

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